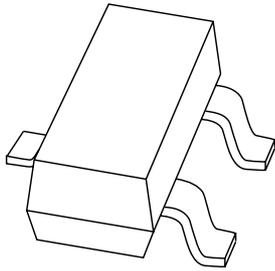


DATA SHEET



BSR13; BSR14 NPN switching transistors

Product data sheet
Supersedes data of 1999 Apr 15

2004 Jan 13

NPN switching transistors

BSR13; BSR14

FEATURES

- High current (max. 800 mA)
- Low voltage (max. 40 V).

APPLICATIONS

- Switching and linear applications.

DESCRIPTION

NPN switching transistor in a SOT23 plastic package.
PNP complements: BSR15 and BSR16.

MARKING

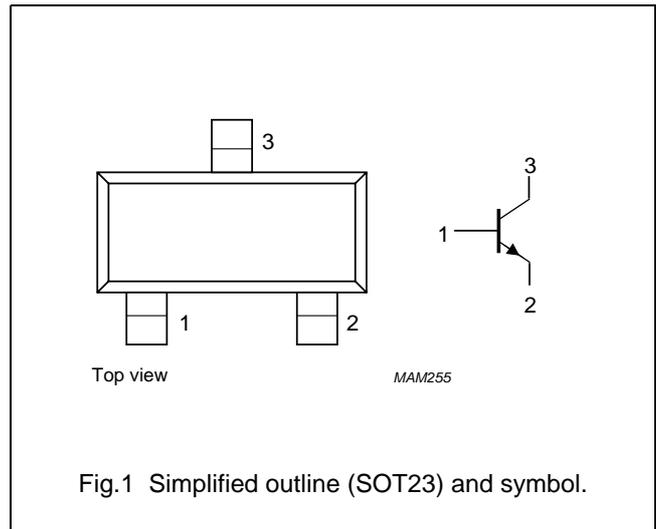
TYPE NUMBER	MARKING CODE ⁽¹⁾
BSR13	U7*
BSR14	U8*

Note

- * = p : Made in Hong Kong.
* = t : Made in Malaysia.
* = W : Made in China.

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
BSR13	-	plastic surface mounted package; 3 leads	SOT23
BSR14			

NPN switching transistors

BSR13; BSR14

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter			
	BSR13		–	60	V
	BSR14		–	75	V
V _{CEO}	collector-emitter voltage	open base			
	BSR13		–	30	V
	BSR14		–	40	V
V _{EBO}	emitter-base voltage	open collector			
	BSR13		–	5	V
	BSR14		–	6	V
I _C	collector current (DC)		–	800	mA
I _{CM}	peak collector current		–	800	mA
I _{BM}	peak base current		–	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	–	250	mW
T _{stg}	storage temperature		–65	+150	°C
T _j	junction temperature		–	150	°C
T _{amb}	operating ambient temperature		–65	+150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICST_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector cut-off current				
	BSR13	I _E = 0; V _{CB} = 50 V	–	30	nA
		I _E = 0; V _{CB} = 50 V; T _j = 150 °C	–	10	μA
	collector cut-off current				
	BSR14	I _E = 0; V _{CB} = 60 V	–	10	nA
		I _E = 0; V _{CB} = 60 V; T _j = 150 °C	–	10	μA
I _{EBO}	emitter cut-off current	I _C = 0; V _{EB} = 5 V			
	BSR13		–	30	nA
	BSR14		–	10	nA

NPN switching transistors

BSR13; BSR14

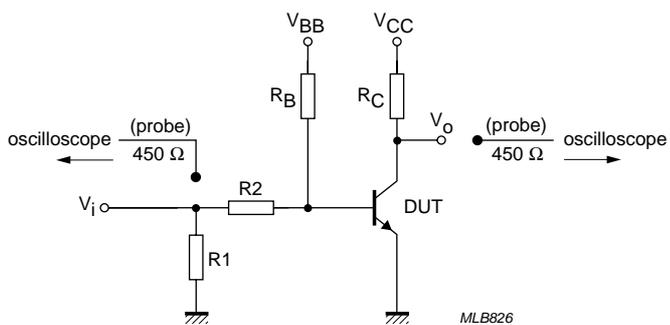
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
h_{FE}	DC current gain	$I_C = 0.1 \text{ mA}; V_{CE} = 10 \text{ V}; \text{note 1}$	35	–	
		$I_C = 1 \text{ mA}; V_{CE} = 10 \text{ V}; \text{note 1}$	50	–	
		$I_C = 10 \text{ mA}; V_{CE} = 10 \text{ V}; \text{note 1}$	75	–	
		$I_C = 150 \text{ mA}; V_{CE} = 10 \text{ V}; \text{note 1}$	100	300	
		$I_C = 150 \text{ mA}; V_{CE} = 1 \text{ V}; \text{note 1}$	50	–	
h_{FE}	DC current gain	$I_C = 500 \text{ mA}; V_{CE} = 10 \text{ V}; \text{note 1}$			
	BSR13		30	–	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 150 \text{ mA}; I_B = 15 \text{ mA}$			
			BSR13	–	400
	BSR14	–	300	mV	
	collector-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}$			
BSR13			–	1.6	V
BSR14	–	1	V		
V_{BEsat}	base-emitter saturation voltage	$I_C = 150 \text{ mA}; I_B = 15 \text{ mA}$			
			BSR13	–	1.3
	BSR14	0.6	1.2	V	
	base-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}$			
BSR13			–	2.6	V
BSR14	–	2	V		
C_c	collector capacitance	$I_E = I_e = 0; V_{CB} = 10 \text{ V}; f = 1 \text{ MHz}$	–	8	pF
f_T	transition frequency	$I_C = 20 \text{ mA}; V_{CE} = 20 \text{ V};$ $f = 100 \text{ MHz}$			
			BSR13	250	–
BSR14	300	–	MHz		
Switching times (between 10% and 90% levels); see Fig.2					
t_{on}	turn-on time	$I_{Con} = 150 \text{ mA}; I_{Bon} = 15 \text{ mA};$ $I_{Boff} = -15 \text{ mA}$	–	35	ns
t_d	delay time		–	15	ns
t_r	rise time		–	20	ns
t_{off}	turn-off time		–	250	ns
t_s	storage time		–	200	ns
t_f	fall time		–	60	ns

Note

1. Pulse test: $t_p \leq 300 \mu\text{s}; \delta \leq 0.02$.

NPN switching transistors

BSR13; BSR14



$V_i = 9.5 \text{ V}$; $T = 500 \text{ } \mu\text{s}$; $t_p = 10 \text{ } \mu\text{s}$; $t_r = t_f \leq 3 \text{ ns}$.
 $R_1 = 68 \text{ } \Omega$; $R_2 = 325 \text{ } \Omega$; $R_B = 325 \text{ } \Omega$; $R_C = 160 \text{ } \Omega$.
 $V_{BB} = -3.5 \text{ V}$; $V_{CC} = 29.5 \text{ V}$.
 Oscilloscope: input impedance $Z_i = \geq 100 \text{ } \Omega$.

Fig.2 Test circuit for switching times.

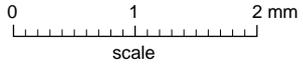
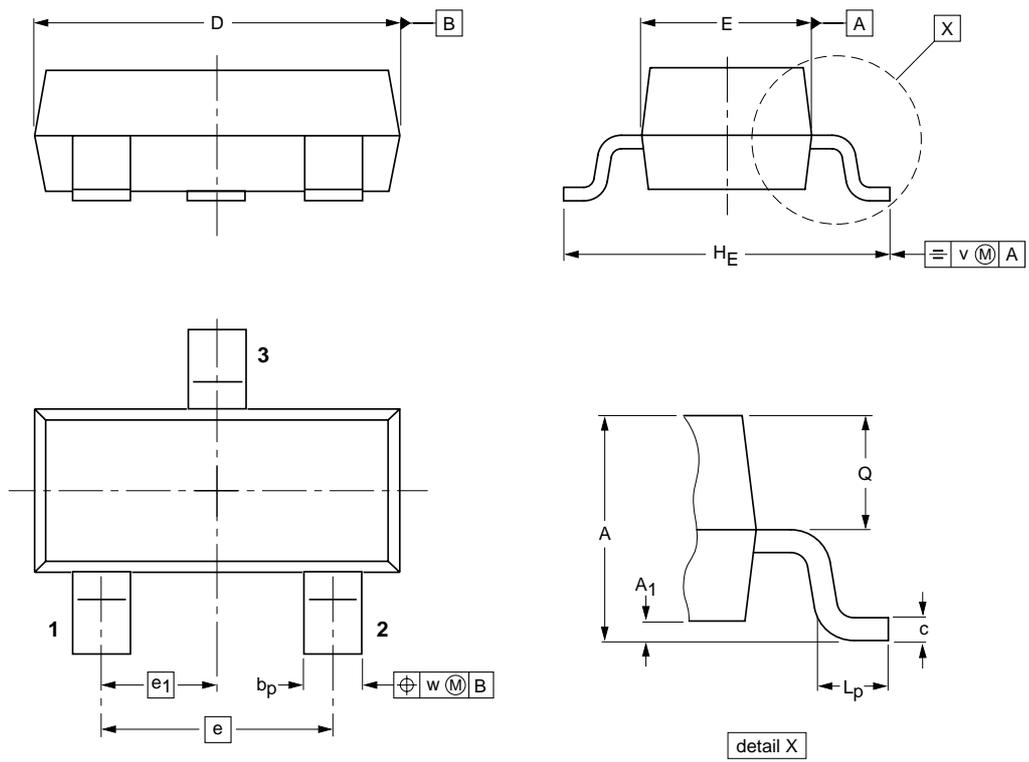
NPN switching transistors

BSR13; BSR14

PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT23



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max.	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT23		TO-236AB				04-11-04 06-03-16

NPN switching transistors

BSR13; BSR14

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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Contact information

For additional information please visit: <http://www.nxp.com>

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Datasheet

(Product Specification)
v.4.0, 2004-01-13
Pages, 139kB

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General description

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NPN switching transistor in a SOT23 plastic package. PNP complements: BSR15 and BSR16.

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Features and benefits

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High current (max. 800 mA)
Low voltage (max. 40 V).

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Applications

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Switching and linear applications.

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Parametrics/similar products

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Type number	Package	h_{FE} [min]	h_{FE} [max]	f_T [min](MHz)	Polarity	Complement	I_C [max](mA)	V_{CEO} [max](V)	P_{tot} [max](mW)	t_{off} (ns)
BSR14	SOT23 (TO-236AB)	40	>40	300	NPN	BSR16	800	40	250	250

Similar products

BSR13_BSR14 links to the similar products page containing an overview of products that are similar in function or related to the type number(s) as listed on this page. The similar products page includes products from the same catalog tree(s), relevant selection guides and products from the same functional category.

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Pricing/ordering/availability

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Type number	Ordering code (12NC)	Orderable part number	Region	Distributor	In stock	Order quantity	Inventory date	Buy online	Samples
BSR14	9335 083 80215	BSR14,215	EU	FARNELL	28,884		6/30/2011	Buy online	Order samples
			AS	element14 APAC	25,070		6/30/2011	Buy online	
			EU	ARROW EUROPE	21,000		6/30/2011	Buy online	
			NA	AVNET ELECTRONICS MARKETING	6,150		6/30/2011	Buy online	
			NA	FUTURE ELECTRONICS	6,000		6/30/2011	Buy online	
			NA	DIGI-KEY CORPORATION	4,590		6/30/2011	Buy online	
			NA	DIGI-KEY CORPORATION	3,000		6/30/2011	Buy online	
			JAPAN	CHIP ONE STOP	yes		6/27/2011	Buy online	
			ASIA	SAC - Taiwan	yes	3000	07/01/2011	Buy online	

The variants in the table below are discontinued. See the table [Discontinued information for more information](#).

Type number	Ordering code(12NC)	Orderable part number	Region	Distributor	In stock	Order quantity	Inventory date	Buy online	Samples
BSR14	9335 083 80235	-	EU	FARNELL	28,884		6/30/2011	Buy online	not available
			AS	element14 APAC	25,070		6/30/2011	Buy online	

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Products/packages

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Type number	Orderable part number	Ordering code (12NC)	Product status	Package	Packing	Marking	ECCN
BSR14	BSR14,215	9335 083 80215	Volume production	SOT23 (TO-236AB)	Tape reel smd	Standard Marking	

The variants in the table below are discontinued. See the table [Discontinued information for more information](#).

Type number	Orderable part number	Ordering code (12NC)	Product status	Package	Packing	Marking	ECCN
BSR14	-	9335 083 80235	Withdrawn Replacement product	SOT23 (TO-236AB)	Tape reel smd	Standard Marking	

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Quality/reliability/chemical content

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Type number	Orderable part number	Chemical content	RoHS	Leadfree conversion date	RHF	IFR (FIT)	MTBF (hours)	MSL	MSL LF
BSR14	BSR14,215	BSR14		week 34, 2003				1	1

The variants in the table below are discontinued. See the table [Discontinued information](#) for more information.

Type number	Orderable part number	Chemical content	RoHS	Leadfree conversion date	RHF	IFR (FIT)	MTBF (hours)	MSL	MSL LF
BSR14	-	BSR14		Always Pb-free					

Quality and reliability disclaimer

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Discontinued information

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Type number	Ordering code (12NC)	Last-time buy date	Last-time delivery date	Replacement product	DN Notice	Status	Comments
BSR14	933508380235	31-dec-04	30-jun-05	PMBT2907A	DN 53	Multi source product Type number fully withdrawn Standard availability	Standard End of Life. Inactive part. See Replacement.

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Design support

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Other type

[Letter Symbols - Transistors; General \(v.1.0, 1999-05-07\)](#)

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